

Preferred Device

Triacs

Silicon Bidirectional Thyristors

Designed primarily for full-wave ac control applications, such as motor controls, heating controls or dimmers; or wherever full-wave, silicon gate-controlled devices are needed.

- High Commutating di/dt and High Immunity to dv/dt @ 125°C
- Uniform Gate Trigger Currents in Three Quadrants, Q1, Q2, and Q3
- Blocking Voltage to 800 Volts
- On-State Current Rating of 16 Amperes RMS at 80°C
- High Surge Current Capability 150 Amperes
- Industry Standard TO-220AB Package for Ease of Design
- Glass Passivated Junctions for Reliability and Uniformity
- Device Marking: Logo, Device Type, e.g., MAC16HCD, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ (T _J = -40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open) MAC16HCD MAC16HCM MAC16HCN	^V drm, Vrrm	400 600 800	Volts
On–State RMS Current (Full Cycle Sine Wave 50 to 60 Hz; T _C = 80°C)	IT(RMS)	16	A
Peak Non-Repetitive Surge Current (One Full Cycle, 60 Hz, TJ = 125°C)	ITSM	150	A
Circuit Fusing Consideration ⁽²⁾ (t = 8.33 ms)	l ² t	93	A ² sec
Peak Gate Power (Pulse Width ≤ 1.0 μs, T _C = 80°C)	PGM	20	Watts
Average Gate Power (t = 8.3 ms, T _C = 80°C)	PG(AV)	0.5	Watts
Operating Junction Temperature Range	Тj	-40 to +125	°C
Storage Temperature Range	Tstg	-40 to +150	°C

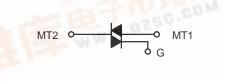
(1) V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



ON Semiconductor

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TRIACS 16 AMPERES RMS 400 thru 800 VOLTS





CASE 221A STYLE 4

PIN ASSIGNMENT				
1	Main Terminal 1			
2	Main Terminal 2			
3	Gate			
4	Main Terminal 2			

ORDERING INFORMATION

Device	Package	Shipping	
MAC16HCD	TO220AB	50 Units/Rail	
MAC16HCM	TO220AB	50 Units/Rail	
MAC16HCN	TO220AB	50 Units/Rail	

Preferred devices are recommended choices for future use and best overall value.



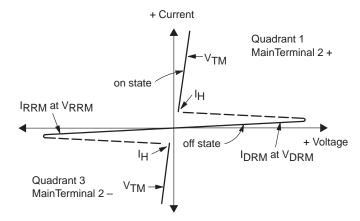
THERMAL CHARACTERISTICS

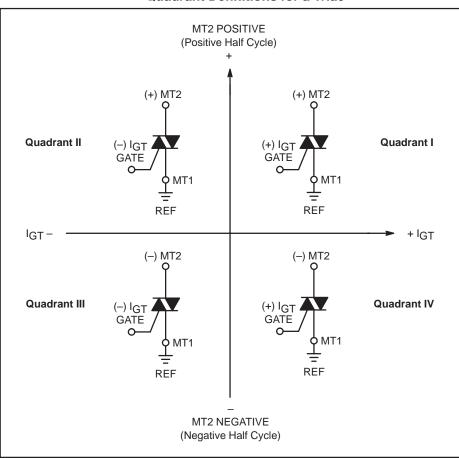
Characteristic Thermal Resistance — Junction to Case — Junction to Ambient			nbol	Value 2.2 62.5	Unit °C/W
			JC JA		
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds			Ľ	260	°C
ELECTRICAL CHARACTERISTICS (TJ = 25°C unless otherwise noted	l; Electricals apply i	n both direc	tions)		
Characteristic	Symbol	Min	Тур	Max	Unit
DFF CHARACTERISTICS		•		•	
Peak Repetitive Blocking Current $T_J = 25^{\circ}C$ $(V_D = Rated V_{DRM}, V_{RRM}, Gate Open)$ $T_J = 125^{\circ}C$	I _{DRM} , I _{RRM}		—	0.01 2.0	mA
ON CHARACTERISTICS					
Peak On–State Voltage ⁽¹⁾ ($I_{TM} = \pm 21$ A Peak)	VTM	—	_	1.6	Volts
Gate Trigger Current (Continuous dc) ($V_D = 12 V$, $R_L = 100 \Omega$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	IGT	10 10 10	16 18 22	50 50 50	mA
Holding Current (V _D = 12 V, Gate Open, Initiating Current = \pm 150 mA)	Ι _Η	—	20	50	mA
Latch Current ($V_D = 12 V$, $I_G = 50 mA$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	ιL		33 36 33	60 80 60	mA
Gate Trigger Voltage (Continuous dc) ($V_D = 12 V$, $R_L = 100 \Omega$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	V _{GT}	0.5 0.5 0.5	0.80 0.73 0.82	1.5 1.5 1.5	Volts
DYNAMIC CHARACTERISTICS					
Rate of Change of Commutating Current ($V_D = 400 \text{ V}$, ITM = 6A, Commutating dv/dt = 20 V/µs, CL = 10 µF Gate Open, T _J = 125°C, f = 250 Hz, with Snubber) LL = 40 mH	(di/dt)c	15	_	_	A/ms
Critical Rate of Rise of Off–State Voltage (V_D = Rated V_{DRM} , Exponential Waveform, Gate Open, T _J = 125°C)	dv/dt	750	—	-	V/µs
Repetitive Critical Rate of Rise of On-State Current IPK = 50 A; PW = 40 μsec; diG/dt = 200 mA/μsec; f = 60 Hz	di/dt	-	_	10	A/μs

(1) Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
VDRM	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
VTM	Maximum On State Voltage
Ι _Η	Holding Current

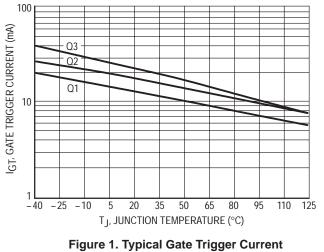


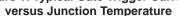


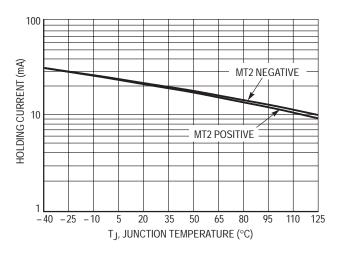
Quadrant Definitions for a Triac

All polarities are referenced to MT1.

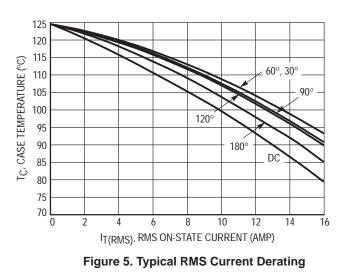
With in-phase signals (using standard AC lines) quadrants I and III are used.











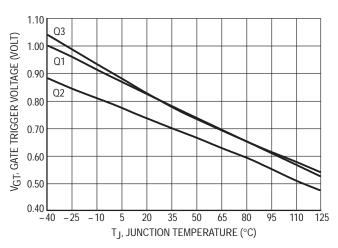


Figure 2. Typical Gate Trigger Voltage versus Junction Temperature

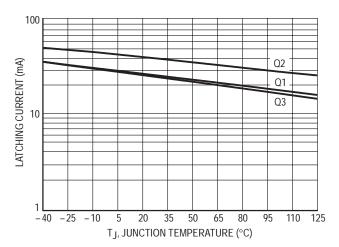


Figure 4. Typical Latching Current versus Junction Temperature

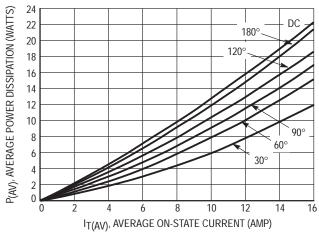


Figure 6. On-State Power Dissipation

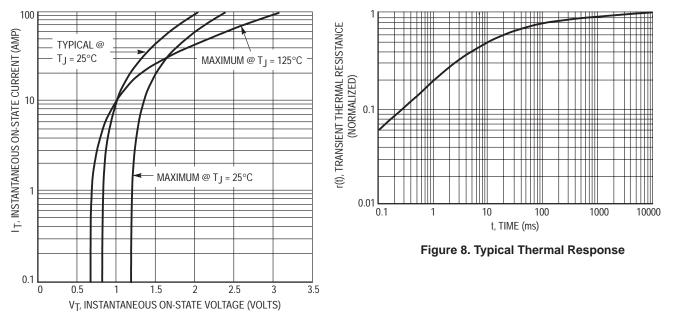
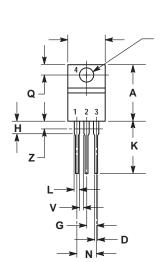
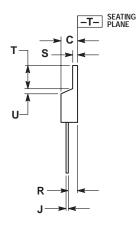


Figure 7. Typical On-State Characteristics

PACKAGE DIMENSIONS

TO-220AB CASE 221A-09 ISSUE Z





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIN	METERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.405	9.66	10.28	
С	0.160	0.190	4.07	4.82	
D	0.025	0.035	0.64	0.88	
F	0.142	0.147	3.61	3.73	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.155	2.80	3.93	
J	0.018	0.025	0.46	0.64	
Κ	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
Ν	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
Т	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
V	0.045		1.15		
Ζ		0.080		2.04	

STYLE 4: PIN 1. MAIN TERMINAL 1 2. MAIN TERMINAL 2 3. GATE 4. MAIN TERMINAL 2

<u>Notes</u>

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